NSN 5962-01-162-1079

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View Online at https://aerobasegroup.com/nsn/5962-01-162-1079

| view entitie at https://ac | |
|----------------------------|--|
| Body Length: | |
| 0.840 inches | |
| Body Width: | |
| Between 0.220 inches a | and 0.310 inches |
| Body Height: | |
| 0.185 inches | |
| Maximum Power Dissi | pation Rating: |
| 739.0 milliwatts | |
| Operating Tempuratur | e Range: |
| -55.0/+125.0 degrees ce | əlsius |
| Storage Tempurature | Range: |
| -65.0/+150.0 degrees ce | elsius |
| End Application: | |
| An/fps-117 radar systen | n |
| Features Provided: | |
| Hermetically sealed and | burn in and bipolar and schottky and programmable and w/enable and w/active pull-up |
| Inclosure Material: | |
| Ceramic | |
| Inclosure Configuratio | ın: |
| Dual-in-line | |
| Output Logic Form: | |
| Transistor-transistor log | ic |
| Input Circuit Pattern: | |
| 10 input | |
| Case Outline Source A | And Designator: |
| D-2 mil-m-38510 | |
| Terminal Surface Trea | tment: |
| Solder | |
| Voltage Rating And Ty | /pe Per Characteristic: |
| 5.5 volts power source | |
| Time Rating Per Chact | teristic: |
| 75.00 nanoseconds pro | opagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level |
| output | |
| Memory Device Type: | |
| Rom | |
| Memory Capacity: | |
| Unknown | |
| Terminal Type And Qu | iantity: |
| 16 printed circuit | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

